Docket No.: 51876P357

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In Re the Application of:

BONG-HWA JEONG

Application No.:

Filed:

For: Semiconductor Memory Device Reducing

Noise

Art Group:

Examiner:

INFORMATION DISCLOSURE STATEMENT UNDER 37 C.F.R. §1.97

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

In accordance with the duty of disclosure, enclosed is a copy of Information Disclosure Statement by Applicant (form PTO/SB/08), which is being submitted concurrently with the Utility Application. It is respectfully requested that the cited references be considered and that the enclosed copy of PTO/SB/08 be initialed by the Examiner to indicate such consideration and a copy thereof returned to applicant(s).

-1- 51876P357

The submission of this Information Disclosure Statement is not to be construed as a representation that a search has been made in the subject application and is not to be construed as an admission that the information cited in this statement is material to patentability.

Please charge any fees due to Deposit Account 02-2666. A duplicate copy of the Fee Transmittal (PTO/SB/17) is enclosed for this purpose.

Respectfully submitted,

BLAKELY, SOKOLOFF, TAYLOR & ZAFMAN LLP

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-2- 51876P357

| Substitute for form 1449A/PTO INFORMATION DISCLOSURE STATEMENT BY APPLICANT (use as many sheets as necessary) | | Complete if Known | | |
|---|----|------------------------|----------------|--|
| | | Application Number | | |
| | | Filing Date | | |
| | | First Named Inventor | Bong-Hwa Jeong | |
| | | Art Unit | | |
| | | Examiner Name | | |
| Sheet | of | Attorney Docket Number | 51876P357 | |

| U.S. PATENT DOCUMENTS | | | | | |
|-----------------------|--------------|---|---|--|---|
| Examiner Initials* | Cite No.1 | Document Number Number - Kind Code ² (if known) | Publication Date or Issue Date MM-DD-YYYY | Name of Patentee or Applicant of Cited Document | Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear |
| | | US-6246620 | 06-12-2001 | Fujioka et al. | |
| | | US-6459964 | 10-01-2002 | Vu et al. | |
| | | US-6088291 | 07-11-2001 | Fujioka et al. | |
| | | US-2001/0021140 | 09-13-2001 | Fujioka et al. | |
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| Cite | Foreign Patent Document | | | Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear | | |
| No.1 | Country Code ³ - Number ⁴ - Kind Code ⁵ (if known) | Publication Date MM-DD-YYYY | Name of Patentee or Applicant of Cited Document | | | |
| | 09-219091 | 08-19-1997 | Samsung Electron Co. Ltd. | | | |
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| | Cite No.1 | Cite No.1 Foreign Patent Document Country Code3 - Number4 - Kind Code5 (if known) | Cite No.¹ Country Code³ - Number⁴ - Kind Code⁵ (if known) Publication Date MM-DD-YYYY | Cite No.¹ Country Code³ - Number⁴ - Kind Code⁵ (if known) Publication Date MM-DD-YYYY Publication Date Applicant of Cited Document | Cite No.¹ Country Code³ - Number⁴ - Kind Code⁵ (if known) Publication Date MM-DD-YYYY Name of Patentee or Applicant of Cited Document Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear | |

| | | _ |
|-----------|------------|------|
| Examiner | Date | |
| Signature | Considered | |

^{*}Examiner: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication.

¹Applicant's unique citation designation number (optional). ²See Kinds Codes of USPTO Patent Documents at www.uspto.gov or MPEP 901.04. ³Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). ⁴For Japanese patent documents, the indication of the year of reign of the Emperor must precede the serial number of the patent document. ⁵Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST. 16 if possible. ⁶Applicant is to place a check mark here if English language Translation is attached.

Information Disclosure Statement

New U.S. Patent Application for SEMICONDUCTOR MEMORY DEVICE REDUCING NOISE Our Ref. No.: P02H6022/US/yh

Reference No.:

- (1) JP Laid-Open No. 09-219091
- (2) US Patent No. 6,246,620
- (3) US Patent No. 6,459,964
- (4) US Patent No. 6,088,291
- (5) US Publication No. 2001/0021140 A1